

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	1,000	>
RMS Reverse Voltage	V _{R(RMS)}	700	V
Average Rectified Output Current @ T _T = +75°C	Io	1.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	25	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Note 5)	$R_{ heta JC}$	13	°C/W
Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	82	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

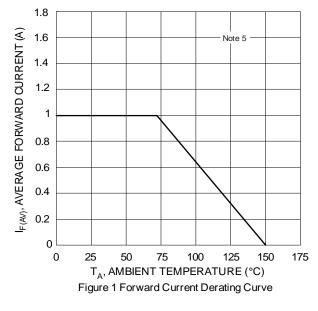
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V _{(BR)R}	1,000	_	_	V	$I_R = 5\mu A$
Forward Voltage Drop	V _F	_	1.1 0.95	1.3 —	V	I _F = 1A, T _J = +25°C I _F = 1A, T _J = +125°C
Leakage Current (Note 6)	I _R	_	0.2 5	10 200	μΑ	$V_R = 1,000V, T_J = +25$ °C $V_R = 1,000V, T_J = +125$ °C
Reverse Recovery Time	t _{rr}	_	240	500	ns	$I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$
Total Capacitance	C _T	_	3	_	pF	$V_R = 4.0V_{DC}$, $f = 1MHz$

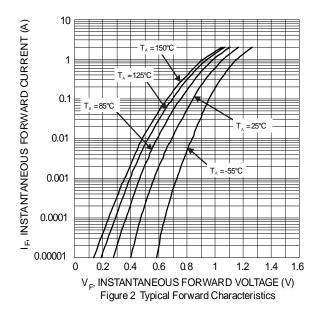
Notes:

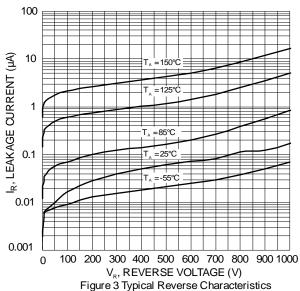
^{5.} Device mounted on FR4 PCB with 1x recommended pad layout, 1-inch 2oz, please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

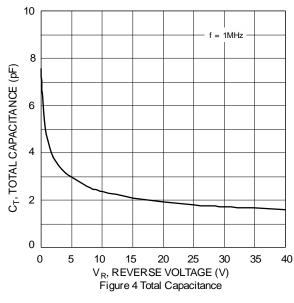
^{6.} Short duration pulse test used to minimize self-heating effect.

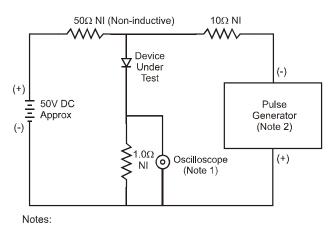


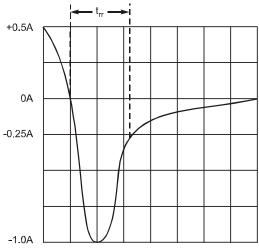












Set time base for 50/100 ns/cm

1. Rise Time = 7.0ns max. Input Impedance = $1.0M\Omega$, 22pF.

2. Rise Time = 10ns max. Input Impedance = 50Ω .

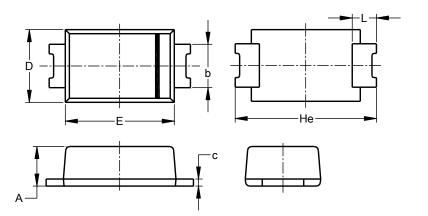
Fig. 5 Reverse Recovery Time Characteristic and Test Circuit



Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

SOD123F (Type B)

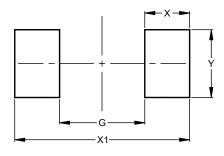


SOD123F (Type B)				
Dim	Min	Max	Тур	
Α	0.81	1.15	_	
b	0.80	1.35	1	
С	0.05	0.30		
D	1.70	1.90	1.80	
Е	2.60	2.80	2.70	
He	3.30	3.70	3.50	
L	0.35	0.85	_	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

SOD123F (Type B)



Dimensions	Value		
Dilliensions	(in mm)		
G	1.90		
Х	1.00		
X1	3.90		
γ	1.50		



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